

# YJ Planar Schottky Barrier Diode Die Specification

60V 20A, 120mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB120M060SS-280A

## Main Products Characteristics

### Maximum Ratings

### Static Electrical Characteristics (Ta = 25°C)

$I_F = 20 \text{ A}$

2%

### Device Schematics and Outline Drawing

Die Thickness \*

Die Size \*\*

Top Metal Pad

Active Area

Top Metal